in Tables 1 and 2 are more than an order of magnitude lower than those previously quoted for Ca_2IrO_4 and $CaIrO_3$. We therefore believe the Ir—O bond length reported here to be more reliable than that determined in the earlier X-ray studies.

This work demonstrates that although absorption of neutrons is a significant problem when working with iridium compounds, the application of an absorption correction makes data refinement to a high standard possible.

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Structure of a Synthetic Double-Layer Silicate, Rb₂Cu₂Si₈O₁₉

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Abstract. $Rb_2Cu_2Si_8O_{19}$, $M_r = 826.7$, monoclinic, $P2_1/m$, a = 11.450 (2), b = 8.409 (2), c = 9.847 (1) Å, $\beta = 95.28 (1)^{\circ}, \quad V = 944.1 (3) \text{ Å}^3, \quad Z = 2,$ 2.91 Mg m⁻³, λ (Mo K α) = 0.71069 Å, $D_{r} =$ $\mu =$ 8.35 mm^{-1} , F(000) = 792, T = 298 K, final R = 0.045for 1411 independent reflections. The structure consists of staggered double sheets of SiO₄ tetrahedra. The sheets consist of six-membered rings. The doubling of sheets forms ten-membered rings viewed parallel to the c axis. These double sheets are linked by pairs of Cu atoms in four coordination sites. Rb atoms are located in the cavities of these tenmembered rings and have eight and ten nearest neighbours. The structure of this silicate is classified as $Rb_2Cu_2\{uB,2_{\infty}^2\}$ [4Si₈O₁₉] after the classification symbol of Liebau [Structural Chemistry of Silicates (1985), pp. 69–75, 121–126, 232, 250, 267. Berlin: Springer].

Introduction. This study was initiated with the purposes of exploring new phases of silicates and contri-

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buting to the crystal chemistry of alkali copper silicates. Until now, two sodium copper silicates (Kawamura & Kawahara, 1976, 1977), a lithium copper silicate (Kawamura, Kawahara & Iiyama, 1978), a potassium copper silicate (Kawamura & Iiyama, 1981) and a caesium copper silicate (Heinrich & Gramlich, 1982) have been investigated. The hydrothermal synthesis of a series of rubidium copper silicates, $Rb_xCu_ySi_pO_q$, was attempted and several new phases were obtained. The present paper reports the structure of one of the newly synthesized phases.

Experimental. Hydrothermal synthesis of the title compound was carried out with a test-tube-type apparatus (723–873 K, 700–2500 kg cm⁻², 3 d) with reagent mixtures of CuSO₄.5H₂O, SiO₂ and Rb₂CO₃. Crystals of Rb₂Cu₂Si₈O₁₉ were deep bluish and less than 0.1 mm in size. The size of the crystal is approximately proportional to the pressure value. The chemical composition of the product was determined by X-ray microprobe analysis. A crystal with dimensions $0.02 \times 0.03 \times 0.01$ mm was used for

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Table 1. Atomic positional parameters $(\times 10^4)$ and equivalent isotropic temperature factors with e.s.d.'s in parentheses

| | $\boldsymbol{B}_{\rm eq} = (4/3) \sum_i \sum_j \boldsymbol{\beta}_{ij} \boldsymbol{a}_i \boldsymbol{a}_j.$ | | | | |
|-------|--|-----------|-----------|----------------------------|--|
| | x | У | Ζ | B_{eq} (Å ²) | |
| Cu | 5185 (1) | 4929 (2) | 8499 (1) | 1.31 (2) | |
| Rb(1) | 4422 (2) | 7500 | 4740 (2) | 3.02 (4) | |
| Rb(2) | 236 (1) | 2500 | 8967 (1) | 2.36 (3) | |
| Si(1) | 2839 (2) | 689 (3) | 6587 (2) | 1.20 (6) | |
| Si(2) | 7414 (2) | 4347 (3) | 741 (2) | 1.30 (6) | |
| Si(3) | 8890 (2) | 663 (3) | 5652 (2) | 1.24 (5) | |
| Si(4) | 2236 (2) | 626 (4) | 1937 (2) | 1.35 (6) | |
| O(1) | 7657 (10) | 2500 | 1110 (10) | 2.32 (27) | |
| O(2) | 5821 (5) | 9729 (9) | 3130 (6) | 1.81 (16) | |
| O(3) | 6065 (5) | 278 (9) | 300 (6) | 1.62 (16) | |
| O(4) | 7733 (6) | 461 (8) | 4640 (6) | 1.56 (15) | |
| O(5) | 0 | 0 | 5000 | 3.00 (29) | |
| O(6) | 8787 (5) | 9779 (9) | 7086 (6) | 1.95 (17) | |
| O(7) | 7882 (5) | 9609 (8) | 2075 (6) | 1.51 (14) | |
| O(8) | 3464 (6) | 5009 (11) | 2476 (6) | 2.41 (18) | |
| O(9) | 1760 (5) | 5179 (10) | 457 (5) | 1.90 (16) | |
| O(10) | 927 (12) | 7500 | 3994 (14) | 4.11 (36) | |
| O(11) | 7438 (10) | 7500 | 3906 (9) | 1.93 (24) | |
| O(12) | 2142 (12) | 2500 | 1619 (13) | 3.79 (37) | |

data collection. The intensity data were collected on a Rigaku AFC-5*R* diffractometer with a generator operated by a rotating anode (40 kV, 200 mA) with graphite-monochromated Mo $K\alpha$ radiation in the $2\theta-\omega$ scan mode. 3 standard reflections, $\overline{1}2\overline{1}$, $\overline{1}2\overline{1}$, $\overline{1}\overline{1}\overline{2}$, were monitored every 150 reflections with a variation of 1.5%. 2434 reflections were collected up to $2\theta = 60^{\circ}$ ($0 \le h \le 16$, $0 \le k \le 11$, $-13 \le l \le 13$), of which 1411 were observed with $I > 3\sigma(I)$. Lorentz-polarization corrections were made but no absorption correction. The cell dimensions were refined from 25 reflections with $27 < 2\theta < 44^{\circ}$.

Preliminary film methods gave $P2_1$ or $P2_1/m$. The existence of centres of symmetry was confirmed from Wilson statistics, so $P2_1/m$ was obtained. The Cu atom was found from Patterson syntheses and the other atoms were located on the subsequent Fourier maps. Full-matrix least-squares refinement with anisotropic temperature factors, minimizing $\sum w(\Delta F)^2$, gave R = 0.045, wR = 0.050, $w = 1/\sigma(F)^2$, S = 0.94, 149 parameters refined, $(\Delta/\sigma)_{max} = 0.14$, $(\Delta\rho)_{max,min} = 1.25$, -1.02 e Å⁻³.

Atomic scattering factors for neutral atoms were used throughout the calculations (from *International Tables for X-ray Crystallography*, 1974, Vol. IV). The final positional parameters and equivalent isotropic thermal factors are shown in Table 1.* Calculations using the modified programs of *UNICS* (Sakurai, 1971) were carried out at the Data Processing Centre of Okayama University. **Discussion.** A stereographic figure using ORTEP (Johnson, 1965) of the structure of $Rb_2Cu_2Si_8O_{19}$ is shown in Fig. 1. This is isostructural with $Cs_2Cu_2-Si_8O_{19}$ (Heinrich & Gramlich, 1982). The structure consists of staggered double sheets of SiO₄ tetrahedra parallel to the *bc* plane. The sheets consist of six-membered rings. They are connected to each other through the apical O atoms of four SiO₄ tetrahedra forming ten-membered rings parallel to the *ac* plane. The mode of linkage of the double sheets is illustrated in Fig. 2. The double sheets are interconnected by Cu_2O_6 units. In these units, Cu atoms have square-planar coordinations with two squares sharing an edge.

The SiO₄ double sheets can be expressed as $Rb_2Cu_2\{uB,2_{\infty}^2\}$ [⁴Si₈O₁₉] after the classification symbol of Liebau (1985). Here, the symbol *uB* stands for 'unbranched' and superscript 2 represents 'two-dimensional framework'. The superscript 4 on Si corresponds to the number of tetrahedra within one



Fig. 1. Stereographic drawing of the structure of $Rb_2Cu_2Si_8O_{19}$. The figure represents the connection of one of the double sheets of SiO₄ tetrahedra with Cu and Rb atoms. Here Si, Cu and Rb atoms correspond to small solid, small open and large open circles, respectively.



Fig. 2. Diagram showing the linkage of the ten-membered rings in double sheets. The large open circles and small solid ones correspond to Rb and Cu atoms, respectively.

^{*} Lists of structure factors and anisotropic thermal parameters have been deposited with the British Library Document Supply Centre as Supplementary Publication No. SUP 55777 (12 pp.). Copies may be obtained through The Technical Editor, International Union of Crystallography, 5 Abbey Square, Chester CH1 2HU, England. [CIF reference: OH1000]

Table 2. Bond lengths (Å) and angles (°) with e.s.d.'s in parentheses

| | - | | |
|---|----------------------------|--|---------------------------|
| Cu-O(2 ⁱ) | 1.894 (6) | Si(3)—O(10 ⁱ) | 1.593 (4) |
| Cu-O(3 ^v) | 1.961 (6) | Si(4)—O(6 ⁱⁱⁱ) | 1.619 (7) |
| Cu-O(3 ⁱⁱ) | 1.965 (5) | $Si(4) \rightarrow O(8^{xiii})$ | 1.551 (7) |
| CuO(8 ⁱⁱⁱ) | 1.895 (7) | $Si(4) \rightarrow O(9^{xiii})$ | 1.653 (6) |
| Si(1)—Ò(2 ⁱⁱⁱ) | 1.574 (6) | Si(4)-O(12) | 1.608 (4) |
| $Si(1) \rightarrow O(4^{xii})$ | 1.637 (7) | $Rb(1) \rightarrow O(2) \times 2^{i}$ | 3.010 (7) |
| Si(1)—O(7 ⁱⁱⁱ) | 1.637 (7) | $Rb(1) \rightarrow O(2) \times 2^{iv,ix}$ | 3.164 (7) |
| $Si(1) - O(11^{i})$ | 1.621 (4) | $Rb(1) - O(4) \times 2^{*,iii}$ | 3.111 (7) |
| Si(2) - O(1) | 1.613 (3) | $Rb(1) \rightarrow O(8) \times 2^{ix}$ | 3.180 (7) |
| $Si(2) \rightarrow O(3^{xiii})$ | 1.597 (6) | $Rb(2) \rightarrow O(6) \times 2^{vi,vii}$ | 3.294 (7) |
| $Si(2) \rightarrow O(7^{ix})$ | 1.629 (6) | $Rb(2) \rightarrow O(7) \times 2^{i,iii}$ | 3.041 (7) |
| $Si(2) \rightarrow O(9^{x^{v}})$ | 1.628 (6) | $Rb(2) - O(9) \times 2^{x.xi}$ | 3.131 (7) |
| Si(3) - O(4) | 1.592 (6) | $Rb(2) \rightarrow O(9) \times 2^{ii,viii}$ | 3.097 (7) |
| $Si(3) \rightarrow O(5^{xiy})$ | 1.577 (3) | $Rb(2) - O(10^{xi})$ | 3.092 (13) |
| $Si(3) \rightarrow O(6^{xvi})$ | 1.610 (7) | $Rb(2) \rightarrow O(12^{*})$ | 3.246 (13) |
| | | | |
| $O(2^i)$ — Cu — $O(3^v)$ | 95.9 (2) | $O(3^{xm})$ —Si(2)— $O(9^{xv})$ |) 111.5 (3) |
| $O(2^{i})$ -Cu-O(8 ⁱⁿ) | 92.0 (3) | $O(7^{1x})$ — $Si(2)$ — $O(9^{xv})$ | 106.4 (4) |
| $O(3^{ii})$ — Cu — $O(3^{v})$ | 79.1 (2) | $O(4) - Si(3) - O(5^{x_1 y})$ | 111.3 (3) |
| $O(3^{ii})$ — Cu — $O(8^{iii})$ | 94.9 (3) | $O(4) - Si(3) - O(6^{xvi})$ | 112.1 (4) |
| $O(2^{iii})$ —Si(1)—O(4* | ⁱⁱ) 108.4 (4) | $O(4)$ — $Si(3)$ — $O(10^{i})$ | 109.0 (5) |
| $O(2^{iii})$ —Si(1)—O(7 ⁱⁱ) | ⁱⁱ) 112.3 (3) | $O(5^{xiv})$ — $Si(3)$ — $O(6^{xv})$ | ⁱ) 108.7 (3) |
| O(2 ⁱⁱⁱ)—Si(1)—O(1) | l ⁱ) 115.1 (5) | $O(5^{xiv})$ — $Si(3)$ — $O(10^{i})$ |) 109.7 (5) |
| $O(4^{xii})$ — $Si(1)$ — $O(7)$ | ⁱⁱⁱ) 107.8 (3) | O(6 ^{xvi})—Si(3)—O(10 ⁱ |) 105.9 (6) |
| $O(4^{xii})$ —Si(1)—O(1 | 1 ⁱ) 106.3 (4) | O(6 ⁱⁱⁱ)—Si(4)—O(8 ^{xiii}) |) 114.0 (4) |
| O(7 ⁱⁱⁱ)—Si(1)—O(11 | l ⁱ) 106.6 (4) | O(6 ⁱⁱⁱ)—Si(4)—O(9 ^{xiii}) |) 103.9 (3) |
| O(1)—Si(2)—O(3 ^{xiii} |) 113.2 (5) | O(6 ⁱⁱⁱ)—Si(4)—O(12) | 106.4 (6) |
| $O(1)$ — $Si(2)$ — $O(7^{ix})$ | 107.5 (4) | O(8 ^{xiii})—Si(4)—O(9 ^{xii} | ⁱⁱ) 112.1 (4) |
| O(1)-Si(2)-O(9** |) 107.4 (5) | O(8 ^{xiii})—Si(4)—O(12 |) 116.5 (6) |
| $O(3^{xiii}) - Si(2) - O(7)$ | ^{ix}) 110.6 (4) | O(9 ^{xiii})—Si(4)—O(12 |) 102.6 (5) |

Symmetry code: (i) 1 - x, $-\frac{1}{2} + y$, 1 - z; (ii) x, $\frac{1}{2} - y$, 1 + z; (iii) 1 - x, 1 - y, 1 - z; (iv) 1 - x, 2 - y, 1 - z; (v) 1 - x, $\frac{1}{2} + y$, 1 - z; (vi) -1 + x, -1 + y, z; (vii) -1 + x, $\frac{3}{2} - y$, z; (viii) -x, 1 - y, 1 - z; (ix) x, $\frac{3}{2} - y$, z; (x) x, y, 1 + z; (xi) -x, $-\frac{1}{2} + y$, 1 - z; (xii) 1 - x, -y, 1 - z; (xiii) x, $\frac{1}{2} - y$, z; (xiv) 1 + x, y, z; (xv) 1 - x, 1 - y, -z; (xvi) x, -1 + y, z.

repeating unit along the shortest period of the cell. CuO_4 squares share corners with SiO₄ tetrahedra. Two kinds of Rb atom site have eight and ten nearest O-atom neighbours, respectively, and are located in the cavity of the six-membered rings.

The interatomic distances and bond angles are listed in Table 2. Si—O and Cu—O distances agree with previous data (Kawamura & Kawahara, 1976,

1977; Kawamura, Kawahara & Iiyama, 1978; Kawamura & Iiyama, 1981; Heinrich & Gramlich, 1982). In the SiO₄ double sheets, the bridging Si-O distance to other Si atoms (mean 1.626 Å) is significantly longer than those to Cu and Rb atoms (mean 1.578 Å). The average Si—O distances for the four SiO₄ tetrahedra are 1.617, 1.617, 1.593 and 1.608 Å, and the distortion indices, $[d(M - O)_{max} - d(M - O)_{max}]$ $O_{min}/(d(M-O))$, of SiO₄ tetrahedra (Liebau, 1985) are 3.92×10^{-2} , 1.98×10^{-2} , 2.02×10^{-2} and 6.34×10^{-2} , respectively. The bonding of SiO₄ tetrahedra and CuO₄ squares is directional and rigid compared with Rb-O polyhedra, which are irregular in shape and have ionic character. Accordingly, the latter are considered to compensate for all the strains resulting from the framework constructed by these rigid and rather covalent sp^3 tetrahedra of SiO₄ and the dsp^2 planar CuO₄ squares. Here the alkali metals may play an important role in the stabilization of the structure. In fact, the number of phases containing $A_x Cu_y Si_p O_q$ (A = alkali metal) is much larger than that containing only $Cu_x Si_p O_q$.

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Structure of Potassium Paradodecatungstate 7¹/₂-Hydrate

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Abstract. $K_{10}[H_2W_{12}O_{42}].7\frac{1}{2}H_2O$, $M_r = 3406.3$, triclinic, $P\bar{1}$, a = 13.126 (2), b = 16.274 (7), $c = \lambda(Mo \ K\alpha) = 0.7107$ Å, $\mu = 280.5$ cm⁻¹, F(000) = 11.756 (4) Å, $\alpha = 96.77$ (2), $\beta = 90.04$ (2), $\gamma = 2982$, T = 296 K, R = 0.051, wR = 0.067 and S = 10.274 (7), c = 10.27

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